Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material: Metal

Overall Length:

0.400 inches

**Overall Diameter:** 

0.424 inches

**Mounting Facility Quantity:** 

1

Internal Configuration:

Junction contact

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

**Overall Width Across Flats:** 

0.437 inches

**Thread Size:** 

0.190 inches

**Criticality Code Justification:** 

Feat

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

2.0 gate trigger voltage, dc and 1.8 on-state voltage, dc

## **Current Rating Per Characteristic:**

7.00 amperes forward current, total rms nanoamperes and 30.00 milliamperes forward current, total rms preset

## **Special Features:**

Item must comply with rqmt of desc production standard no. L00845; junction pattern arrangement: pnpn

Thread Series Designator:

Unf

Terminal Type And Quantity:

1 threaded stud and 2 tab, solder lug

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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